

MMBF4416

N-Channel RF Amplifiers • This device is designed for RF amplifiers.

- Sourced from process 50.



Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{DG}	Drain-Gate Voltage	30	V
V _{GS}	Gate-Source Voltage	-30	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Junction and Storage Temperature Range	- 55 ~ 150	°C

Electrical Characteristics $T_A=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristics		1	l.	•	•
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$V_{DS} = 0, I_{G} = 1\mu A$	-30			V
I _{GSS}	Gate Reverse Current	$V_{GS} = -20V, V_{DS} = 0$ $V_{GS} = -20V, V_{DS} = 0, T_A = 150^{\circ}C$			-1 -200	nA nA
V _{GS} (off)	Gate Source Cut-off Voltage	$V_{DS} = 15V, I_{D} = 1nA$	-2.5		-6	V
V _{GS}	Gate Source Voltage	$V_{DS} = 15V, I_{D} = 0.5mA$	-1		-5.5	V
On Chara	cteristics	•			•	•
I _{DSS}	Zero-Gate Voltage Drain Current	V _{GS} = 15V, V _{GS} = 0	5		15	μΑ
V _{GS} (f)	Gate-Source Forward Voltage	$V_{DS} = 0$, $I_G = 1mA$			1	V
Small Sign	nal Characteristics	·				
IY _{fs} I	Forward Transfer Admittance	$V_{DS} = 15V, V_{GS} = 0, f = 1KHz$	4500		7500	μmhos
ly _{os} l	Output Admittance	$V_{DS} = 15V, V_{GS} = 0, f = 1KHz$			50	μmhos
C _{iss}	Input Capacitance	$V_{DS} = 15V, V_{GS} = 0, f = 1MHz$			4	РF
Crss	Reverse Transfer Capacitance	$V_{DS} = 15V, V_{GS} = 0, f = 1MHz$			0.9	РF
C _{oss}	Output Capacitance	$V_{DS} = 15V, V_{GS} = 0, f = 1MHz$			2	РF
Functiona	I Characteristics	·				
NF	Noise Figure	$V_{DS} = 15V$, $I_D = 5mA$, $R_g = 100\Omega$, $f = 100MHz$			2	dB
G _{ps}	Common Source Power Gain	$V_{DS} = 15V, I_{D} = 5mA, R_{g} = 100\Omega,$ f = 100MHz	18			dB

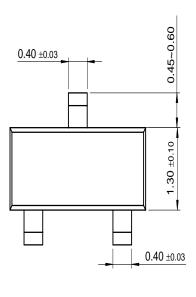
Thermal Characteristics $T_A=25$ °C unless otherwise noted

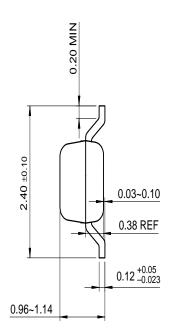
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	225	mW
	Derate above 25°C	1.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	556	°C/W

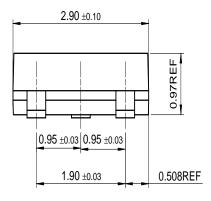
* Device mounted on FR-4 PCB 1.6" × 1.6" × 0.06".

Package Dimensions

SOT-23







Dimensions in Millimeters

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